Evidence for a single hydrogen molecule connected by an atom ic chain

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(Dated: April 15, 2024)

Stable, single-m olecule conducting-bridge con gurations are typically identi ed from peak structures in a conductance histogram. In previous work on Pt with H_2 at cryogenic temperatures it has been shown that a peak near 1 G₀ identi es a single molecule PtH₂-Pt bridge. The histogram shows an additional structure with lower conductance that has not been identi ed. Here, we show that it is likely due to a hydrogen decorated Pt chain in contact with the H_2 molecular bridge.

PACS numbers: 73.63 Rt, 63.22.+ m, 73.23.-b, 85.65.+ h

The interest in chains of single metal atom s bridging between two electrodes is largely due to their unique properties as idealone-dimensional system s [1]. For clean metals, only Au, Pt and Ir form atom ic chains [2, 3]. However, atom ic or molecular adsorption on metal surfaces can widen this scope. Recently, 2 nm long Ag atom ic chains have been created in the presence of oxygen at ultra low temperature, while clean Ag only form s short chains [4]. Atom ic chains have been in aged by transm ission electron microscope (TEM) for the noble metals Cu, Ag, and Au [5, 6, 7, 8].

These atom ic wires could form ideal leads to organic m olecules for the investigation of their potential use in m olecular electronics [9]. The rst experiments contacting m olecules by Pt atom ic leads appear to indicate that atom ic chain form ation is suppressed by the molecular adsorption [10, 11]. In the latter works it was shown that a single hydrogen m olecule, H₂, can be contacted between Pt leads. The hydrogen molecule is a valuable model system for single-molecule junctions. By use of point contact spectroscopy, isotope substitution and shot noise measurements the system was characterized in great detail. and close agreement with atom istic model calculations was obtained [10, 11]. The Pt-H2-Pt junction was rst identi ed by its conductance. It shows up as a recurring plateau in the conductance when controllably breaking a contact, and in a histogram of conductance values collected for many such breakings it gives rise to a sharp peak near 1 G₀, where 1 G₀ = $2e^2 = h$ is the conductance quantum. This main peak at 1 G_0 for the Pt/H₂ system is therefore well understood. However, there is more structure in the conductance histogram for the Pt/H₂ junctions, which has not been explained. In particular, a strong peak is found at about 0.1-0.2 G₀, suggesting that other con gurations of hydrogen between Pt leads may be form ed. In the present study we focus on those structures, having a conductance below 1 G_0 , and we present evidence that they can be attributed to the form ation of a hydrogen decorated Pt atom ic chain, that form s one of the leads contacting a hydrogen m olecule.

The measurements have been performed using the mechanically controllable break junction technique (see Ref. 12 for a detailed description). Once under vacuum and cooled to 42 K a ne Ptwire was broken. Atom icsized contacts between the wire ends can be form ed using a piezo element for ne adjustment. H₂ was admitted via a capillary. DC two-point voltage-biased conductance m easurem ents were perform ed by applying a voltage in the range from 10 to 150 m V. Every statistical data set (such as a conductance histogram) was build from a large num ber (over 3000) of individual digitized conductance traces. AC voltage bias conductance m easurem ents were perform ed using a standard lock-in technique. The conductance was recorded for xed contact con guration using an acm odulation of 1 m V am plitude and a frequency of 7.777 kHz, while slow ly ram ping the DC bias between -100 and + 100 m V.

Figures 1 (a) and (b) show typical conductance traces for clean Pt and for Pt after adm itting H2. A fter adm itting H_2 , plateaux near 1G₀ are frequently observed and the corresponding histogram (Fig. 1(c)) shows a sharp feature near 1 G $_0$. The plateaux near 1G $_0$ and the corresponding peak in the histogram originate from singlem olecule Pt-H2-Pt contacts, as shown by previous studies [10, 11]. In addition to the 1G $_0$ feature, the histogram shows a peak near $0.2 \, \text{G}_0$ on top of a low-conductance tail. Looking at the individual traces, we nd that the conductance does not suddenly drop, as expected for a contact break after the appearance of the plateau near 1G₀, but rather decreases by sm all steps while the contact is being stretched. This suggests that a structure having a conductance below 1G₀ is formed by further stretching the single-molecule Pt-H2-Pt contact. The conductance trace in Fig. 1 (b) shows that the structure can be stretched to quite long lengths (> 0.5 nm in Fig. 1(b)), which suggests the form ation of an atom ic chain.

In order to investigate the chain form ation, we measure the length histogram of the last plateau and the return length distribution. Figure 2(a) shows the length histogram for the nalconductance plateaux for the Pt/H₂

contacts (lled grey distribution), and this is com pared to a length histogram for clean Pt. The length for Pt/H_2 is taken here as the distance between the points at which the conductance drops below $1.3 \, \text{G}_0$ and $0.1 \, \text{G}_0$, respectively, while for clean Pt the boundaries are $2.5 \, \text{G}_0$ and 1.0 G_0 . The form er boundaries are set such as to capture the length of the 1G₀-plateau plus the subsequent structures that give rise to the peak around $0.2 \, \text{G}_0$ in the conductance histogram . It is striking that the Pt/H_2 contact can be stretched as long as 0.8 nm . A sequence of peaks is observed in the Pt/H₂ length histogram of Fig. 2(a), indicating the repeated occurrence of certain stable chain con gurations that we identify as (A), (B), and (C). The distance between the peaks is 0.27 0.01 nm, which is slightly larger than the Pt-Pt distance of a clean Pt atom ic chain (0.23 nm) [3].

The inset of Fig.2 (a) shows the average return lengths as a function of chain length. This is the distance over which the two electrodes need to be m oved back after the junction breaks in order to re-establish contact, averaged over m any break cycles. Apart from an o set of 0.3 nm due to the elastic response of the banks [3], the relation is approximately proportional, suggesting that a fragile structure is form ed w ith a length corresponding to that of the last plateau, which is unable to support itself when it breaks and collapses onto the banks on either side.

W e further test this interpretation by analyzing the stretch length dependence of the conductance and by point contact spectroscopy. Figure 2(b) shows the average conductance for Pt/H_2 junctions as a function of the chain length. The curve is obtained by adding all m easured conductance traces from the start value (1.3 G₀) onward, and dividing at each length by the num ber of traces included at that point. The m ean conductance decreases rapidly as the chain becom es longer. A lthough the conductance for a pure Pt chain also decreases with length [13] its conductance stays well above 1 G₀. This fact, com bined with the larger peak distance in the length histogram indicate that the structure with low er conductance tance is probably not a clean Pt atom ic chain, and m ay



FIG.1: B reaking and return traces for clean Pt (a), and for Pt in a H₂ atm osphere (b). M any of such curves are collected into conductance histogram s as shown in (c) for clean Pt (black curve) and Pt in H₂ (lled graph).



FIG.2: (a) Length histogram for clean Pt (black curve) and Pt in H_2 (lled graph). The start and stop values between which the lengths were measured were taken as (2.5, 1.0) for Pt and (1.3, 0.1) for Pt/H₂, in units of G₀. Inset: A verage return lengths as a function of chain length. (b) A verage conductance as a function of chain length for Pt/H₂. (c) D i erential conductance (top) and its derivative (bottom) for a Pt/H₂ contact taken at a conductance of 0.1 G₀.

be due to a hydrogen decorated atom ic chain. The average conductances of structures (A), (B), and (C) are 0.96, 0.56 and 0.28 G₀, respectively. Since the conductance of structure (A) is close to $1 G_0$, we identify it with the single m olecule PtH₂-Pt contacts that have been studied previously [10, 11]. We discuss the new structures (B) and (C) that arise by further stretching of the Pt-H₂-Pt junction in the follow ing. Note that a stable level near 0.2-0.3 G₀ is observed at 0.6-0.8 nm in length in Fig. 2 (b). The slow length dependence gives rise to a high num ber of counts in a conductance histogram, which explains the peak at 0.2 G₀ in Fig. 1 (c). Apart from this stable structure that we have labelled (C) the length histogram points at an interm ediate structure (B), for which the conductance varies m ore strongly with stretching.

Figure 2 (c) shows an example of the di erential conductance and its derivative for a Pt/H_2 contact taken at a conductance of $0.1 \, \text{G}_0$. The spectrum shows an increase in the di erential conductance sym m etrically at 51 m eV, and clear sym m etric peaks are observed in the second derivative, $d^2 I = dV^2$. The sym m etric peaks are com monly observed near 57 4 m eV in the second derivatives for contacts having conductances in the range 0.6-0.1 G₀. Note that the sign of the signal in Fig. 2 (c) agrees with that for inelastic electron tunnelling spectroscopy, as expected for low conductance [14]. How ever, most signals that we nd are of the type discussed in Ref. 15. The energy of 57 m eV agrees with the energy of the transverse translation mode of the molecule in the Pt-H-H-Pt con guration [11]. The close agreem ent suggest that a hydrogen molecule is still bridging the junction after stretching it beyond the $1 G_0$ plateau.

Based on the experiments presented above we arrive at the following chain formation model for Pt atom ic contacts with H_2 . First, a single hydrogen molecule is



FIG. 3: (Color online) Transm ission functions for the proposed structures (B) (green/gray curve) and (C) (black curve), respectively, as calculated from DFT for a setup with bulk electrodes and a (111) surface with a pyram id of Pt atom s on top. The zero point of the x-axis is the Ferm ienergy. The explicit geom etries of the structures are shown as insets.

adsorbed between Pt electrodes (structure A). Further stretching induces the incorporation of the rst Pt atom from the stem part of the electrode into the chain (structure B). Then, the second Pt atom is incorporated into the chain (structure C), and the atom ic chain is form ed with a single hydrogen molecule bridging. The larger distances in the length histogram and the low conductance should then be attributed to additional hydrogen decorating the Pt atom ic chain. Further support for this chain form ation process is obtained from density functional theory (DFT) calculations.

E lectronic structure calculations were perform ed using a plane wave in plementation of DFT [16] with an energy cuto of 340 eV, where we used ultra-soft pseudopotentials [17], and a PW 91 param etrization for the exchange and correlation functional [18]. The transm ission functions of the molecular junctions were calculated using a general non-equilibrium Green's function formalism for phase-coherent electron transport [19], where both, the G reen's function of the scattering region and the selfenergies describing the coupling to the sem i-in nite electrodes, were evaluated in terms of a basis consisting of maximally localized W annier functions [20]. In our calculations the supercells for the scattering region are de ned by 3 3 atoms in the surface plane and contain three to four surface layers on each side of the molecule. We used a 4 grid for the k-point integration in order to obtain well converged results for the conductance [21].

B ased upon the distances and conductances found in the experim ent presented above we came to consider the m odel structures for (B) and (C) illustrated by the insets in Fig. 3. The gure shows calculated transm ission functions for structures (B) and (C) as a function of energy. The transm ission function for structure (A), a hydrogen bridge with no additional hydrogen having a conductance of 1 G₀ [22] is low ered when going from (A) to (C). The conductances are found as 0.46 and 0.15 G₀ for structures (B) and (C), respectively, which is in reasonable agreement with the experimental values of 0.6 and 0.3 G₀. The theoretical values have been obtained after optimizing the distance between the contacts by total energy minimization and the optimial length of a Pt wire segment decorated with additional hydrogen was found to be 0.272 nm which agrees with the experimental results.

Our analysis shows that this reduction is due to the additional hydrogen atom s saturating the s-orbital and part of the d-orbitals between the Pt atom s they are attached to, thereby making them unavailable for electron transport. This is illustrated in Fig. 4 (a) that shows the results of calculations for the H₂ bridge structure without additional hydrogen. We have simulated the e ect hydrogen addition m ight have by cutting out PtW annier functions from the scattering Ham iltonian. The rem oval of the Pts-orbital for one and two subsequent wire atom s (shown only for the rst case in Fig. 4 (a)) accounts for the successive reduction of the transmission at around 1 eV and higher above the Ferm i level. For the reduction of the transm ission directly at E $_{\rm F}\,$ and therefore the conductance, also a blocking of som e of the d-orbitals is needed, which is also shown in Fig. 4(a). A lthough a cutting of the d-W annier functions of the rst Pt-atom alone does not have a large e ect on the conductance and seem s to even enhance it, the conductance is drastically reduced if both the s- and d-orbitals of the same Pt atom are blocked. For structure (B) we also compared the transm ission functions of the atom ic wire system with that of the more realistic surface calculation in Fig. 3. Qualitatively, the results are similar in terms of the main peak structure illustrating that the analysis is robust with respect to details of the atom ic arrangem ent. In a quantitative com parison, how ever, the conductance from the surface calculation is higher than for the wire system by approximately a factor 2.0.

In Fig. 4 (b) we show the dependence of the conductance with increasing the distance between the wire electrodes. In these calculations the positions of all hydrogen atoms and four Pt atoms on each side have been fully relaxed. The corresponding binding energy of the H_2 bridge molecule to the wires is also shown for com – parison. A lthough there is a short plateau in the conductance for structure (B) when stretched beyond the optim al bonding distance (green/grey curves in Fig. 4 (b)), for structure C (black curves) the overall decrease with the length seems to be slower up to a stretching length of 0.1 nm. This trend was also found in the experim entalhistogram. The shift in optim al distance between (B) and (C) just re ects the increase of the total cell length due to the expansion of a second wire segment.

Let us comment on the path that may lead to the structures discussed above. Since the bridging H_2 molecule is very weakly bound to the Pt electrodes, 'wire pulling'



FIG. 4: (Color online) (a) Transm ission functions obtained from calculations of a single H_2 bridge between wires of Pt atom s with the s-orbital (solid black curve), the d-orbitals (dashed green/grey curve), both the s- and d-orbitals (solid green/grey curve) and no atom ic orbitals (dashed black line) rem oved from the H am iltonian. The rem oved orbitals are also shown superim posed with the atom ic positions in the insets. (b) C onductance (solid curves) and binding energy (dashed curves) for the m olecule inside the junction for structures sim ilar to (B) (green/grey) and (C) (black) assumed to have linear atom ic wire arrangements as shown in the insets.

seems to be unlikely. Structures (B) and (C) can only be formed by a concerted process. Such a process may involve the displacement of Pt atoms at the surface due to phonons and the formation of intermediate structures with the additional hydrogen adsorbed on the electrodes. The conguration space for covering all possibilities for atom ic movements in such a process is too large to be explored by our calculations in detail.

In conclusion, the experim ental evidence shows that a $Pt-H_2-Pt$ single-m olecule junction can be stretched further into form ing an atom ic wire. We propose a likely structure for this wire in term s of a Pt atom ic chain decorated with hydrogen. This interpretation is supported by DFT calculations. While the pathway that brings new atom s into the atom ic chain structure remains problem – atic, we obtain fair agreement in the numbers for the bond distances and the conductances.

W e are very gratefulto K .W .Jacobsen for his support and for m any stim ulating discussions. This work is part of the research program of the Stichting FOM, which is nancially supported by NW O. The Center for A tom icscale M aterials Physics at N anoD TU is sponsored by the D anish N ational Research Foundation. W e acknow ledge support from the N ano-Science Center at the University of C openhagen and from the D anish C enter for Scienti c C om puting through G rant N o. H DW -1101-05.

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